





Winbond Electronics Corporation




W978H2KBQX2E

Part Number:	W978H2KBQX2E
Fabrikant / Brand:	Winbond Electronics Corporation
Produkt beschreibung	IC DRAM 256M PARALLEL 168WFBGA
Datebanken:	 W978H2KBQX2E.pdf
RoHs Status	 Bleif gratis / RoHS kompatibel
Ship From	Hong Kong
Shipment Way	DHL/Fedex/TNT/UPS/EMS

UFRO FIR ZITAT

Bild kann Representatioun sinn. Kuckt Spezifikatioune fir Produktdetailer.


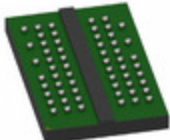
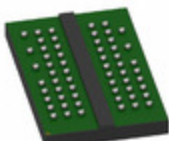


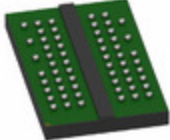
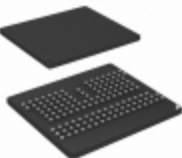
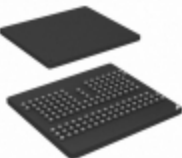
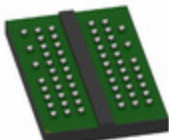


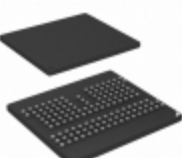
Spezifikatioune vun W978H2KBQX2E

PART NUMBER	W978H2KBQX2E
HIERSTELLER	Winbond Electronics Corporation
BESCHREIWUNG	IC DRAM 256M PARALLEL 168WFBGA
BLEIF FREE STATUS / ROHS STATUS	Bleif gratis / RoHS kompatibel
DATENLABEL	 W978H2KBQX2E.pdf
SCHREIWE CYCLE TIME - WORD, PAGE	15ns
VOLTAGE - SUPPLY	1.14 V ~ 1.95 V
TECHNOLOGIE	SDRAM - Mobile LPDDR2
SUPPLIER DEVICE PACKAGE	168-WFBGA (12x12)
SERIE	-
VERPAKUNG	Tray
PACKAGE / CASE	168-WFBGA
OPERATIOUN TEMPERATUR	-25°C ~ 85°C (TC)
MOUNTING TYPE	Surface Mount
FEUCHTIGKEIT SENSIBILITÉITNIVEAU (MSL)	3 (168 Hours)
GEDÄCHTNIS TYPE	Volatile
SPÄICHERGRÉISST	256Mb (8M x 32)
MEMORY INTERFACE	Parallel
MEMORY FORMAT	DRAM
BLEIF FREE STATUS / ROHS STATUS	Lead free / RoHS Compliant
DETAILBESCHREIWUNG	SDRAM - Mobile LPDDR2 Memory IC 256Mb (8M x 32) Parallel 400MHz 168-WFBGA (12x12)
CLOCK FREQUENCY	400MHz

Verbonnen Tags

Winbond Electronics Corporation W978H2KBQX2E	W978H2KBQX2E Distributeur	W978H2KBQX2E Ubidder
W978H2KBQX2E Präis	W978H2KBQX2E Fotoen	W978H2KBQX2E Bild
W978H2KBQX2E PDF Dateblatt	W978H2KBQX2E Luet Dateblatt	W978H2KBQX2E Dateblatt
W978H2KBQX2E Stock	Kaaft W978H2KBQX2E	Kaaft Winbond Electronics Corporation W978H2KBQX2E
Winbond Electronics Corporation W978H2KBQX2E	Winbond Electronics Corporation Ubidder	Winbond Electronics Corporation Distributeur
Winbond Electronics Corporation W978H2KBQX2E	Winbond W978H2KBQX2E	Winbond Electronics W978H2KBQX2E

Verbonnen Produkter

<div></div> <div>W978H6KBQX2I Produzenteuren: Winbond Electronics Corporation Beschreibung: IC DRAM 256M PARALLEL 168WFBGA Op Lager: Out stock</div> <div>RFQ</div>	<div></div> <div>W9751G8KB25I Produzenteuren: Winbond Electronics Corporation Beschreibung: IC DRAM 512M PARALLEL 60WBGA Op Lager: Out stock</div> <div>RFQ</div>
<div></div> <div>W9751G8KB-25 Produzenteuren: Winbond Electronics Corporation Beschreibung: IC DRAM 512M PARALLEL 60WBGA Op Lager: 107 pcs</div> <div>RFQ</div>	<div></div> <div>W978H6KBQX2E Produzenteuren: Winbond Electronics Corporation Beschreibung: IC DRAM 256M PARALLEL 168WFBGA Op Lager: Out stock</div> <div>RFQ</div>
<div></div> <div>W978H2KBQX2I Produzenteuren: Winbond Electronics Corporation Beschreibung: IC DRAM 256M PARALLEL 168WFBGA Op Lager: Out stock</div> <div>RFQ</div>	<div></div> <div>W9751G8KB-25 TR Produzenteuren: Winbond Electronics Corporation Beschreibung: IC DRAM 512M PARALLEL 60WBGA Op Lager: Out stock</div> <div>RFQ</div>
<div></div> <div>W978H6KBVX2E Produzenteuren: Winbond Electronics Corporation Beschreibung: IC DRAM 256M PARALLEL 134VFBGA Op Lager: Out stock</div> <div>RFQ</div>	<div></div> <div>W978H2KBVX2I Produzenteuren: Winbond Electronics Corporation Beschreibung: IC DRAM 256M PARALLEL 134VFBGA Op Lager: Out stock</div> <div>RFQ</div>
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<div></div> <div>W9751G6KB25I Produzenteuren: Winbond Electronics Corporation Beschreibung: IC DRAM 512M PARALLEL 84WBGA Op Lager: 225 pcs</div> <div>RFQ</div>	<div></div> <div>W978H2KBVX2E Produzenteuren: Winbond Electronics Corporation Beschreibung: IC DRAM 256M PARALLEL 134VFBGA Op Lager: Out stock</div> <div>RFQ</div>